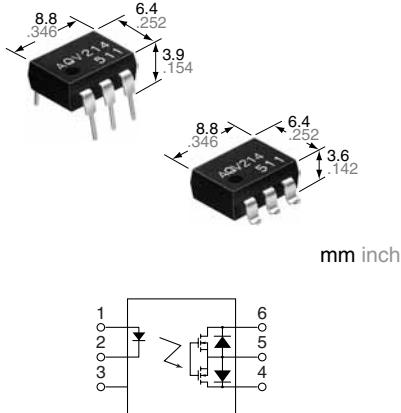


**6-pin type for switching  
low-level analog signal**

**PhotoMOS®  
GU 1 Form A  
(AQV21O, AQV214H)**

## FEATURES



**RoHS compliant**

**1. Controls low-level analog signals**  
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

**2. Controls various types of loads**  
such as relays, motors, lamps and solenoids

**3. Optical coupling for extremely high isolation**

Unlike mechanical relays, the PhotoMOS combines LED and optoelectronic device to transfer signals using light for extremely high isolation.

**4. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side**

**5. Stable on-resistance**

**6. Low-level off state leakage current of max. 1 μA**

**7. Reinforced insulation type of I/O voltage 5,000V also available**

## TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computers

## TYPES

I/O isolation	Output rating*	Output rating*		Package	Part No.				Packing quantity		
		Load voltage	Load current		Through hole terminal		Surface-mount terminal				
					Tube packing style		Tape and reel packing style	Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC dual use	Standard 1,500 V AC	60V	550 mA	DIP6-pin	AQV212	AQV212A	AQV212AX	AQV212AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.	
		100 V	320 mA		AQV215	AQV215A	AQV215AX	AQV215AZ			
		200 V	180 mA		AQV217	AQV217A	AQV217AX	AQV217AZ			
		350 V	130 mA		AQV210	AQV210A	AQV210AX	AQV210AZ			
		400 V	120 mA		AQV214	AQV214A	AQV214AX	AQV214AZ			
		600 V	50 mA		AQV216	AQV216A	AQV216AX	AQV216AZ			
	Reinforced 5,000 V	400 V	120 mA		AQV214H	AQV214HA	AQV214HAX	AQV214HAZ			

\*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

## RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

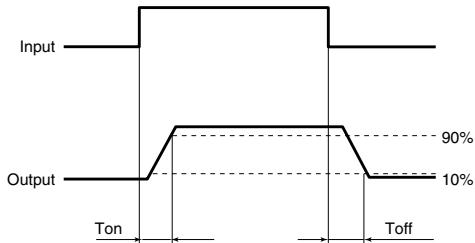
Item		Symbol	Type of connection	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Remarks	
Input	LED forward current	I <sub>F</sub>	A	50 mA							f = 100 Hz, Duty factor = 0.1%	
	LED reverse voltage	V <sub>R</sub>		5 V								
	Peak forward current	I <sub>FP</sub>		1 A								
	Power dissipation	P <sub>in</sub>		75 mW								
Output	Load voltage (peak AC)	V <sub>L</sub>	B	60 V	100 V	200 V	350 V	400 V	600 V	400 V	A connection: Peak AC, DC B, C connection: DC	
	Continuous load current	I <sub>L</sub>		0.55 A	0.32 A	0.18 A	0.13 A	0.12 A	0.05 A	0.12 A		
	Peak load current	I <sub>peak</sub>		0.65 A	0.42 A	0.22 A	0.15 A	0.13 A	0.06 A	0.13 A		
	Power dissipation	P <sub>out</sub>	C	0.80 A	0.60 A	0.30 A	0.17 A	0.15 A	0.08 A	0.15 A	A connection: 100 ms (1 shot), V <sub>L</sub> =DC	
Total power dissipation		P <sub>T</sub>	1.2 A		0.96 A	0.54 A	0.4 A	0.3 A	0.15 A	0.3 A		
I/O isolation voltage		V <sub>iso</sub>	500 mW		550 mW							
Temperature limits	Operating	T <sub>opr</sub>	1,500 V AC		5,000 V AC							
	Storage	T <sub>stg</sub>	-40°C to +85°C		-40°F to +185°F		-40°C to +100°C		-40°F to +212°F		Non-condensing at low temp.	

# GU 1 Form A (AQV21O, AQV214H)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection**	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Condition	
Input	LED operate current	Typical	I <sub>fon</sub>	—	1 mA	1 mA	1 mA	1 mA	1 mA	1.3 mA	I <sub>L</sub> = Max.	
	Maximum	—		—	3 mA	3 mA	3 mA	3 mA	3 mA	3 mA		
Input	LED turn off current	Minimum	I <sub>foff</sub>	—	0.4 mA	0.4 mA	0.4 mA	0.4 mA	0.4 mA	0.4 mA	I <sub>L</sub> = Max.	
	Typical	—		—	0.79 mA	0.79 mA	0.79 mA	0.79 mA	0.79 mA	0.79 mA		
Input	LED dropout voltage	Typical	V <sub>F</sub>	—	1.25 V (1.14 V at I <sub>F</sub> = 5 mA)						I <sub>F</sub> = 50 mA	
	Maximum	—		—	1.5 V							
Output	On resistance	Typical	R <sub>on</sub>	A	0.83 Ω	2.3 Ω	11.0 Ω	23 Ω	30 Ω	70 Ω	30 Ω	I <sub>F</sub> = 5 mA
	Maximum	—			2.5 Ω	4.0 Ω	15.0 Ω	35 Ω	50 Ω	120 Ω	50 Ω	I <sub>L</sub> = Max. Within 1 s on time
	On resistance	Typical	R <sub>on</sub>	B	0.44 Ω	1.15 Ω	5.5 Ω	11.5 Ω	22.5 Ω	55 Ω	22.5 Ω	I <sub>F</sub> = 5 mA
	Maximum	—			1.25 Ω	2.0 Ω	7.5 Ω	17.5 Ω	25 Ω	100 Ω	25 Ω	I <sub>L</sub> = Max. Within 1 s on time
	On resistance	Typical	R <sub>on</sub>	C	0.25 Ω	0.6 Ω	2.8 Ω	6.0 Ω	11.3 Ω	28 Ω	11.3 Ω	I <sub>F</sub> = 5 mA
	Maximum	—			0.63 Ω	1.0 Ω	3.8 Ω	8.8 Ω	12.5 Ω	50 Ω	12.5 Ω	I <sub>L</sub> = Max. Within 1 s on time
	Output capacitance	Typical	C <sub>out</sub>	A	150 pF	110 pF	70 pF	45 pF	45 pF	45 pF	45 pF	I <sub>F</sub> = 0 mA V <sub>B</sub> = 0 V f = 1 MHz
	Off state leakage current	Maximum	I <sub>Leak</sub>	—	1 μA						—	I <sub>F</sub> = 0 mA V <sub>L</sub> = Max.
Transfer characteristics	Turn on time*	Typical	T <sub>on</sub>	—	0.65 ms	0.6 ms	0.25 ms	0.25 ms	0.21 ms	0.28 ms	0.6 ms	I <sub>F</sub> = 5 mA**
	Maximum	—		—	2 ms	2 ms	1.0 ms	0.5 ms	0.5 ms	0.5 ms	0.8 ms	I <sub>L</sub> = Max.
	Turn off time*	Typical	T <sub>off</sub>	—	0.08 ms	0.06 ms	0.05 ms	0.05 ms	0.05 ms	0.04 ms	0.05 ms	I <sub>F</sub> = 5 mA
	Maximum	—		—	0.2 ms	0.2 ms	0.2 ms	0.2 ms	0.2 ms	0.2 ms	0.2 ms	I <sub>L</sub> = Max.
	I/O capacitance	Typical	C <sub>iso</sub>	—	0.8 pF						—	f = 1 MHz
	Maximum	—		—	1.5 pF						—	V <sub>B</sub> = 0 V
	Initial I/O isolation resistance	Minimum	R <sub>iso</sub>	—	1,000 MΩ						—	500 V DC

\*Turn on/Turn off time



## RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I <sub>F</sub>	Standard type: 5 Reinforced type: 5 to 10	mA

### For Dimensions.

### For Schematic and Wiring Diagrams.

### For Cautions for Use.

These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

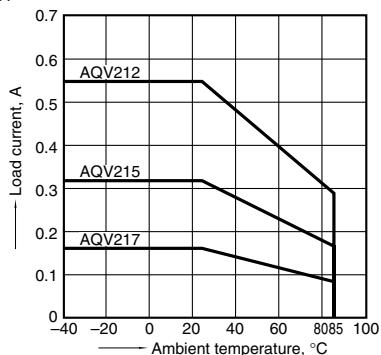
# GU 1 Form A (AQV21O, AQV214H)

## REFERENCE DATA

### 1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$   
 $-40^{\circ}\text{F}$  to  $+185^{\circ}\text{F}$

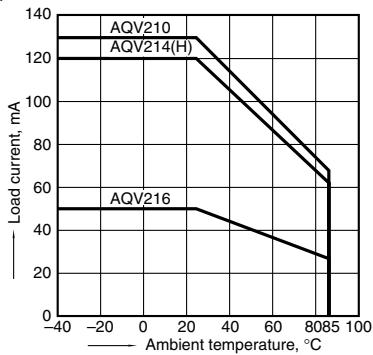
Type of connection: A



### 1-(2). Load current vs. ambient temperature characteristics

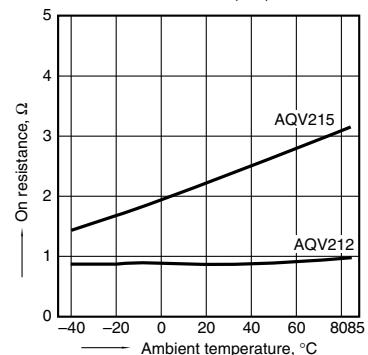
Allowable ambient temperature:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$   
 $-40^{\circ}\text{F}$  to  $+185^{\circ}\text{F}$

Type of connection: A



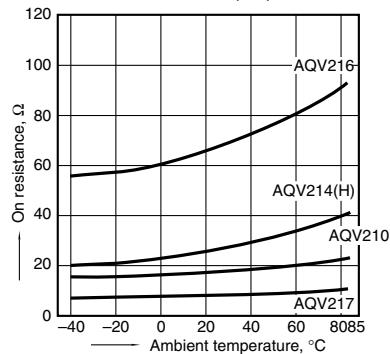
### 2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;  
LED current: 5 mA; Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



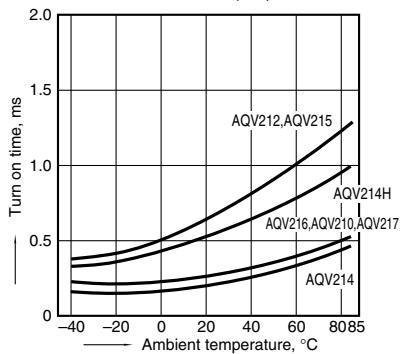
### 2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;  
LED current: 5 mA; Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



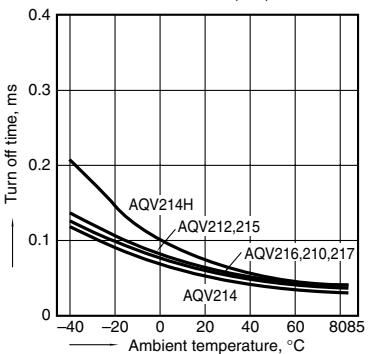
### 3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;  
Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



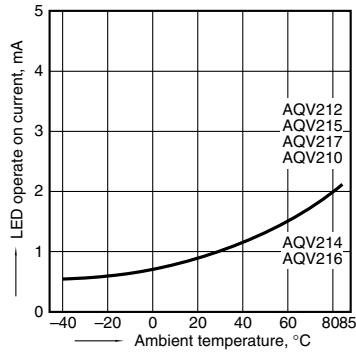
### 4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA;  
Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



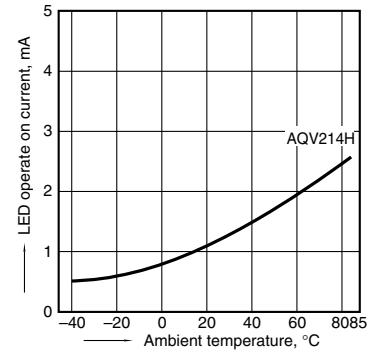
### 5-(1). LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



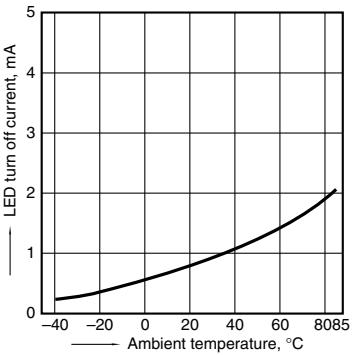
### 5-(2). LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);  
Continuous load current: Max. (DC)



### 6-(1). LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);  
Continuous load current: Max. (DC)

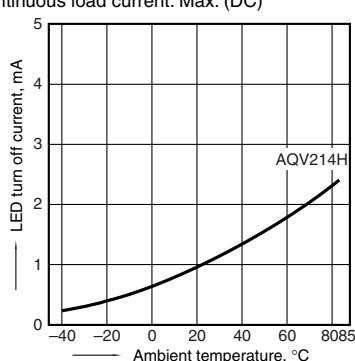


# GU 1 Form A (AQV21○, AQV214H)

## 6-(2). LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);

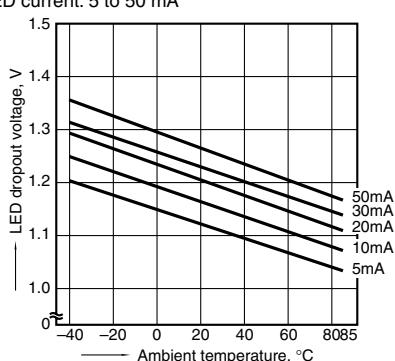
Continuous load current: Max. (DC)



## 7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types

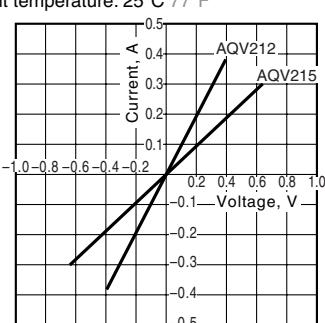
LED current: 5 to 50 mA



## 8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;

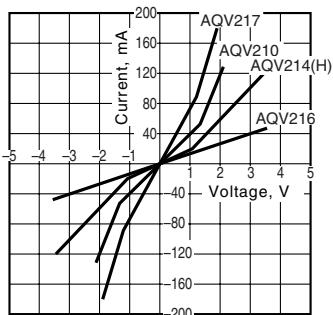
Ambient temperature: 25°C 77°F



## 8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;

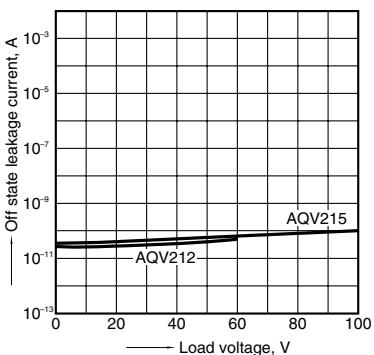
Ambient temperature: 25°C 77°F



## 9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;

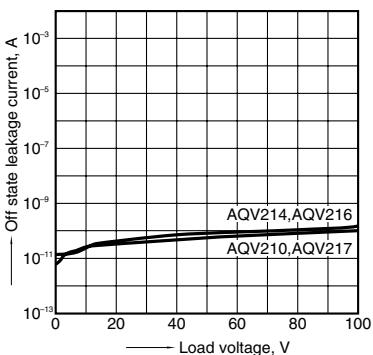
Ambient temperature: 25°C 77°F



## 9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;

Ambient temperature: 25°C 77°F

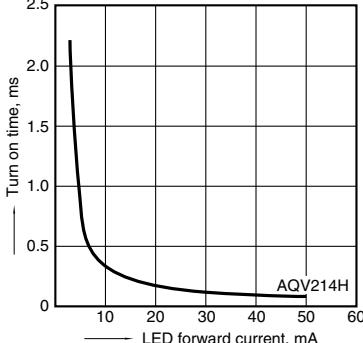
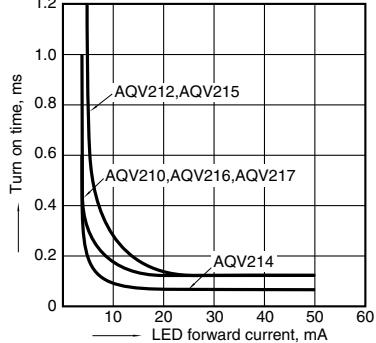


## 10-(1). Turn on time vs. LED forward current characteristics

## 10-(2). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;

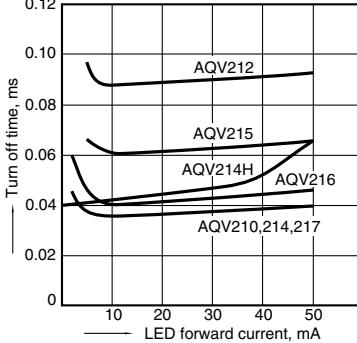
Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



## 11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;

Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



## 12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;

Frequency: 1 MHz; Ambient temperature: 25°C 77°F

